

# N-Channel Super-junction MOSFET Gen I

## MOSFET

Metal Oixde Semiconductor Field Effect Transistor

## 650V Super-junction Gen I

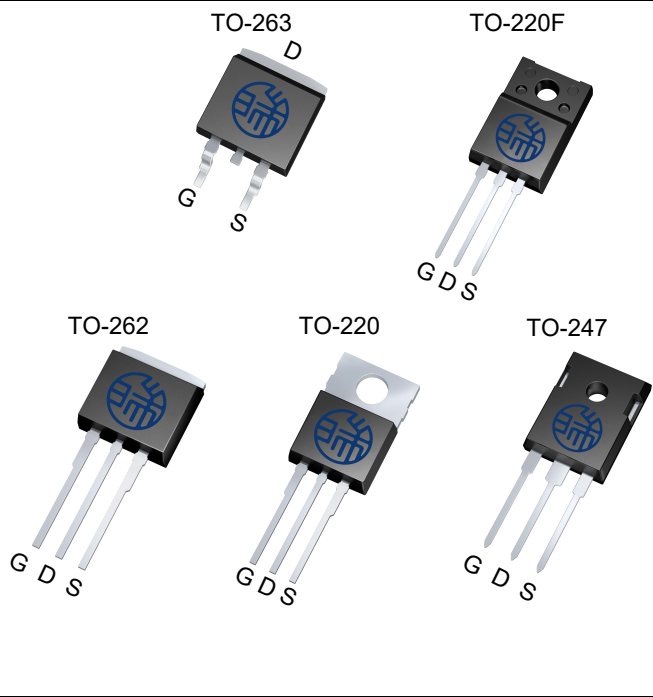
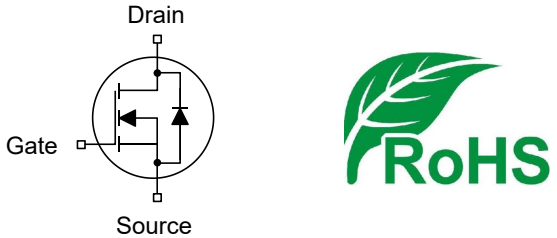
650V Super-junction Gen I Power Transistor

## HRM65R105Fx Data Sheet

Rev. 2020 V2.0



## 650V Super-junction Power MOSFET Gen I

<p><b>Description</b></p> <p><b>650V Super-junction MOSFET Gen I</b></p> <p>Super-junction MOSFET Gen I is designed by HR-Micro Semiconductor Company, according to the SJ principle. This device provide an excellent Gate charge and <math>R_{DS(on)}</math>, which leads to extremely communication and conduction losses .So it is very suitable for AC/DC power conversion, Laptop adapter, Lighting, and industrial power applications.</p>		
<p><b>Features</b></p> <ul style="list-style-type: none"> <li>● Very low FOM <math>R_{DS(on)} \times Q_g</math></li> <li>● 100% avalanche tested</li> <li>● Easy to use/drive</li> <li>● Ultra-fast body diode</li> <li>● RoHS compliant</li> </ul>		
<p><b>Applications</b></p> <ul style="list-style-type: none"> <li>● Switch Mode Power Supply (SMPS)</li> <li>● Uninterruptible Power Supply (UPS)</li> <li>● Suitable for hard and soft switching (PFC and high performance LLC)</li> <li>● Telecom and Solar inverter</li> </ul>		
<p><b>Key Performance Parameters</b></p>		
<p><b>Parameter</b></p>	<p><b>Value</b></p>	<p><b>Unit</b></p>
<p><math>V_{DS} @ T_{j,max}</math></p>	<p>700</p>	<p>V</p>
<p><math>R_{DS(on),max}</math></p>	<p>0.105</p>	<p><math>\Omega</math></p>
<p><math>Q_{g,typ}</math></p>	<p>64.5</p>	<p>nC</p>
<p><math>I_D</math></p>	<p>40</p>	<p>A</p>
<p><math>I_{D,pulse}</math></p>	<p>120</p>	<p>A</p>
<p><math>E_{OSS} @ 400V</math></p>	<p>7.98</p>	<p><math>\mu J</math></p>
<p>Body Diode <math>di_f/dt</math></p>	<p>900</p>	<p>A/<math>\mu s</math></p>
<p><b>Device Marking and Package Information</b></p>		
<p><b>Device</b></p>	<p><b>Package</b></p>	<p><b>Marking</b></p>
<p>HRM65R105FB</p>	<p>TO-263</p>	<p>65R105FB</p>
<p>HRM65R105FF</p>	<p>TO-220F</p>	<p>65R105FF</p>
<p>HRM65R105FL</p>	<p>TO-262</p>	<p>65R105FL</p>
<p>HRM65R105FP</p>	<p>TO-220</p>	<p>65R105FP</p>
<p>HRM65R105FW</p>	<p>TO-247</p>	<p>65R105FW</p>

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ , unless otherwise noted			
Parameter	Symbol	Value	Unit
Drain-Source voltage( $V_{GS}=0\text{V}$ )	$V_{DS}$	650	V
Continuous Drain Current <sup>1)</sup>	$I_D$	$T_C = 25^\circ\text{C}$	40
		$T_C = 100^\circ\text{C}$	24
Pulsed Drain Current <sup>2)</sup>	$I_{D,pulse}$	120	A
Gate-Source Voltage	$V_{GS}$	$\pm 30\text{V}$	V
Single Pulse Avalanche Energy	$E_{AS}$	796	mJ
Repetitive Avalanche Energy	$E_{AR}$	1.2	mJ
Avalanche Current	$I_{AR}$	6.6	A
MOSFET dv/dt Ruggedness, $V_{DS} = 0 \dots 480\text{V}$	dv/dt	50	V/ns
Power Dissipation For TO-263、TO-262、TO-220、TO-247	$P_D$	278	W
Power Dissipation For TO-220F		35	
Continuous Diode Forward Current	$I_S$	40	A
Diode Pulsed Current <sup>2)</sup>	$I_{S,pulse}$	120	
Reverse Diode dv/dt <sup>3)</sup>	dv/dt	50	V/ns
Maximum Diode Commutation Speed	di <sub>r</sub> /dt	900	A/ $\mu\text{s}$
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55~+150	$^\circ\text{C}$

Thermal Resistance For TO-263、TO-262、TO-220、TO-247			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{thJC}$	0.45	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	$R_{thJA}$	62	

Thermal Resistance For TO-220F			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{thJC}$	3.6	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	$R_{thJA}$	80	

**Notes**

- 1) Limited by maximum junction temperature.
- 2) Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3) Identical low side and high side switch with identical  $R_G$ .

Electrical Characteristics $T_J = 25^\circ\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	650	--	--	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 650V$ $V_{GS} = 0V, T_J = 25^\circ\text{C}$	--	--	4	$\mu A$
		$V_{DS} = 650V$ , $V_{GS} = 0V, T_J = 150^\circ\text{C}$	--	--	4000	
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 30V$	--	--	$\pm 100$	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	3.0	4.0	5.0	V
Drain-Source On-State-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 20A$	--	0.092	0.105	$\Omega$
Gate Resistance	$R_G$	$f = 1.0\text{MHz}$ open drain	--	3	--	$\Omega$
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V$ , $V_{DS} = 100V$ $f = 1.0\text{MHz}$	--	2940	--	$\mu F$
Output Capacitance	$C_{oss}$		--	102	--	
Reverse Transfer Capacitance	$C_{rss}$		--	3.5	--	
Total Gate Charge	$Q_g$	$V_{DD} = 520V, I_D = 40A$ $V_{GS} = 10V$	--	64.5	--	nC
Gate-Source Charge	$Q_{gs}$		--	20.0	--	
Gate-Drain Charge	$Q_{gd}$		--	25.4	--	
Gate Plateau Voltage	$V_{Plateau}$		--	6.6	--	V
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 400V, I_D = 40A$ $R_G = 15\Omega, V_{GS} = 10V$	--	20	--	ns
Turn-on Rise Time	$t_r$		--	15	--	
Turn-off Delay Time	$t_{d(off)}$		--	70	--	
Turn-off Fall Time	$t_f$		--	8	--	
<b>Drain-Source Body Diode Characteristics</b>						
Body Diode Forward Voltage	$V_{SD}$	$T_J = 25^\circ\text{C}, I_{SD} = 20A$ , $V_{GS} = 0V$	--	1.0	1.5	V
Reverse Recovery Time	$t_{rr}$	$V_R = 400V$ $I_F = 20A, di_F/dt = 100A/\mu s$	--	165	--	ns
Reverse Recovery Charge	$Q_{rr}$		--	1.2	--	$\mu C$
Peak Reverse Recovery Current	$I_{rrm}$		--	14	--	A

Typical Characteristics  $T_J = 25^\circ\text{C}$ , unless otherwise noted

Figure 1. Transient Thermal Impedance For TO-263/262/220/247

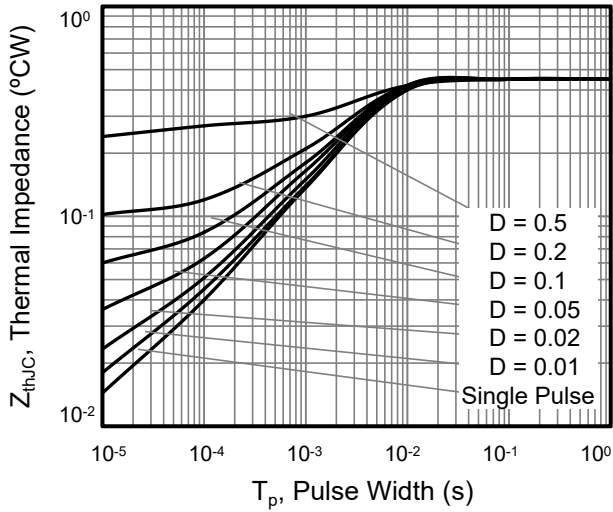


Figure 2. Transient Thermal Impedance For TO-220F

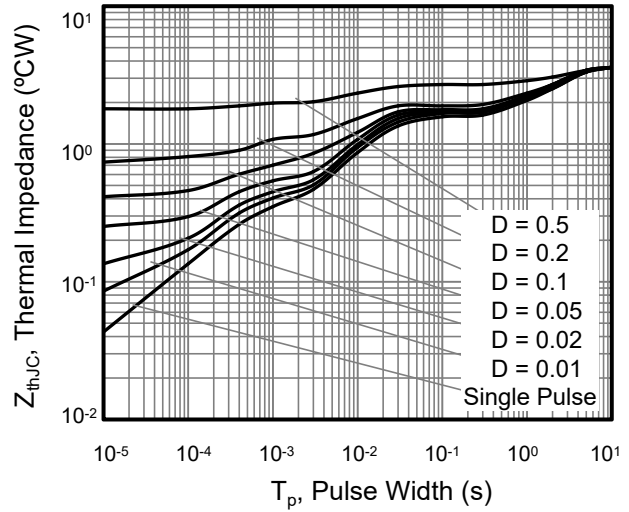


Figure 3. Safe Operation Area For TO-263/262/220/247

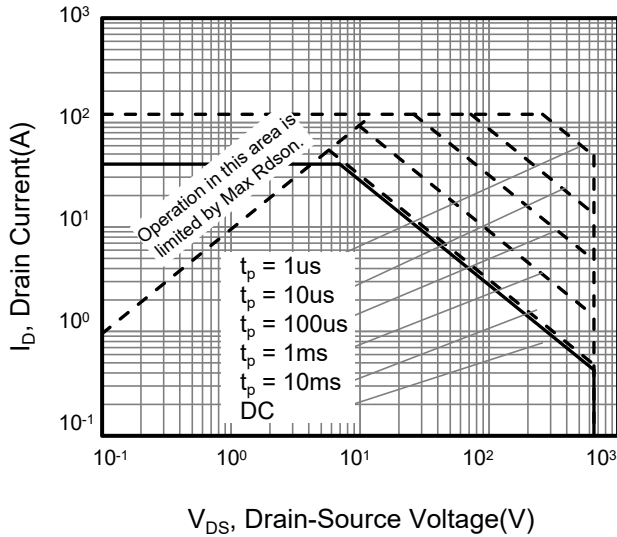


Figure 4. Safe Operation Area For TO-220F

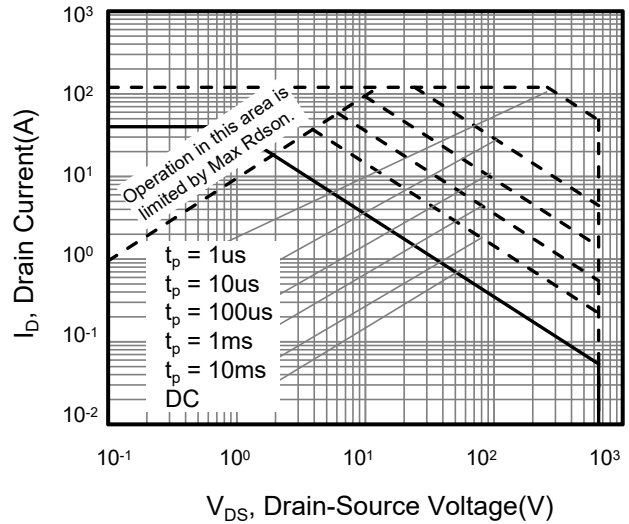


Figure 5. Output Characteristics

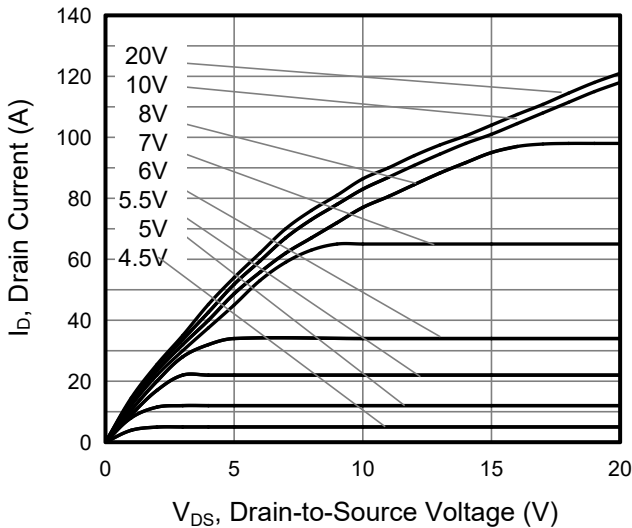
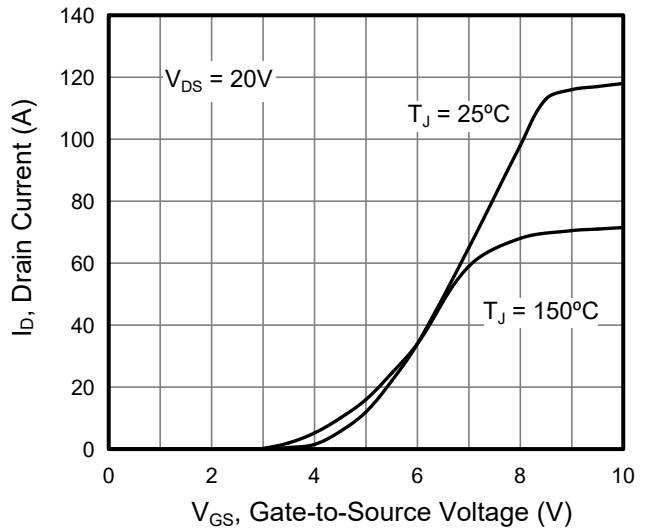


Figure 6. Transfer Characteristics



Typical Characteristics  $T_J = 25^\circ\text{C}$ , unless otherwise noted

Figure 7. On-Resistance vs. Drain Current

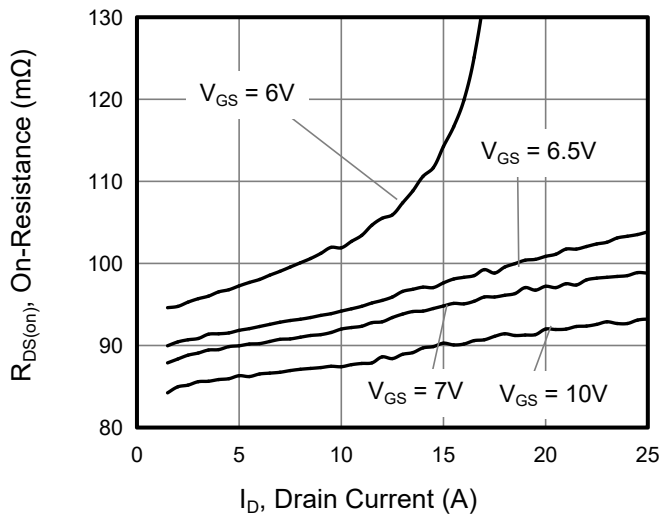


Figure 8. Capacitance

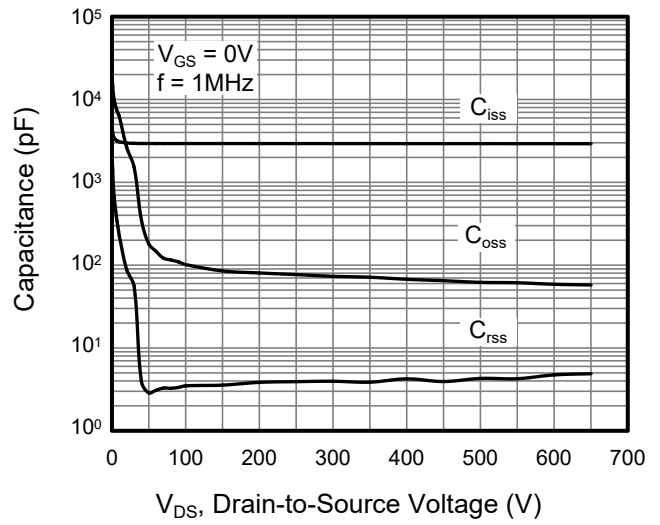


Figure 9. Gate Charge

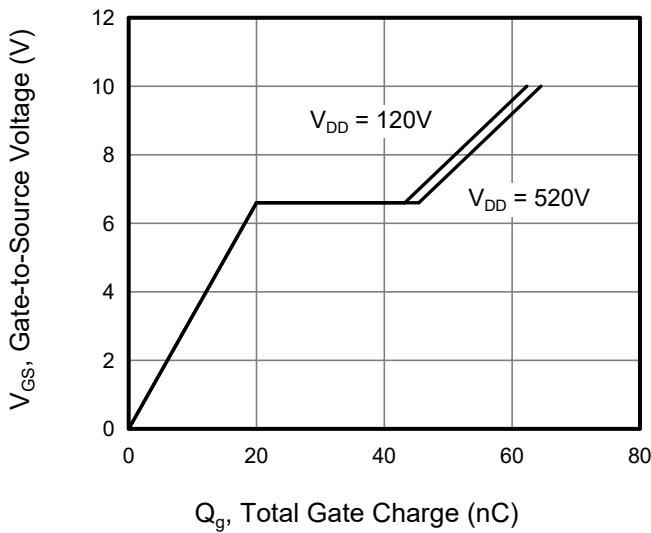


Figure 10. Body Diode Forward Voltage

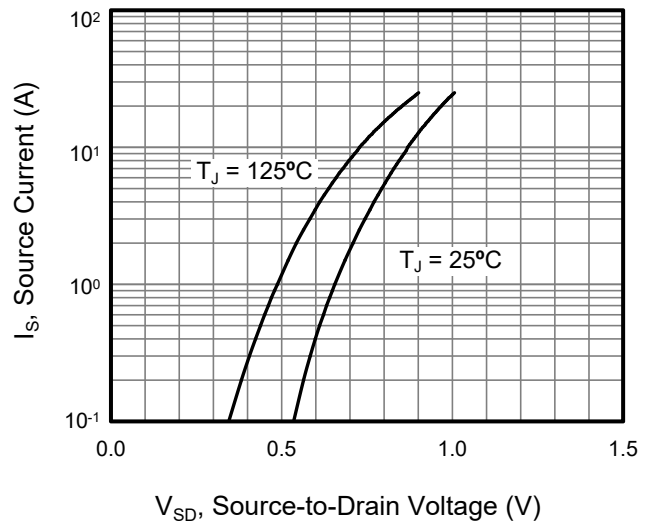


Figure 11. Typ. Coss Stored Energy

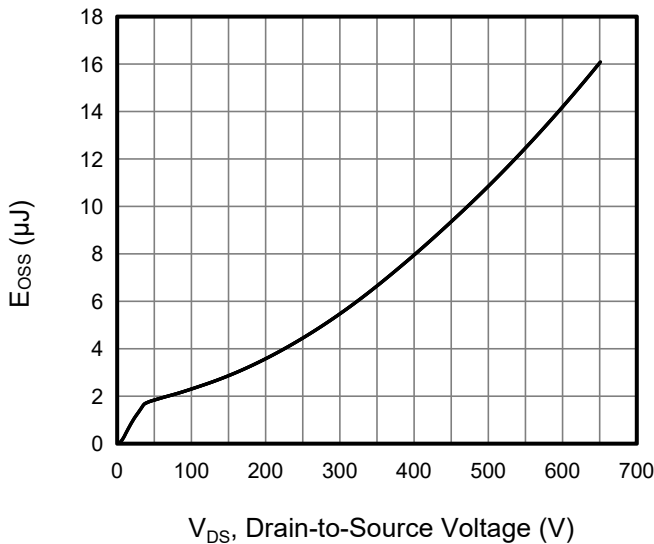
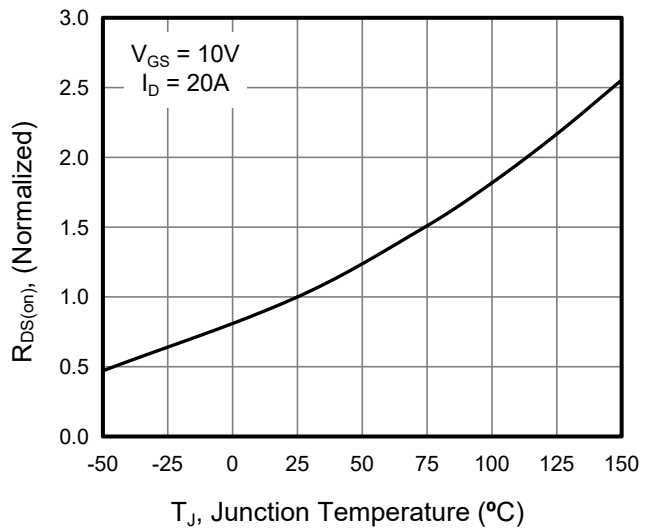


Figure 12. On-Resistance vs. Temperature



Typical Characteristics  $T_J = 25^\circ\text{C}$ , unless otherwise noted

Figure 13. Breakdown Voltage vs. Junction Temperature

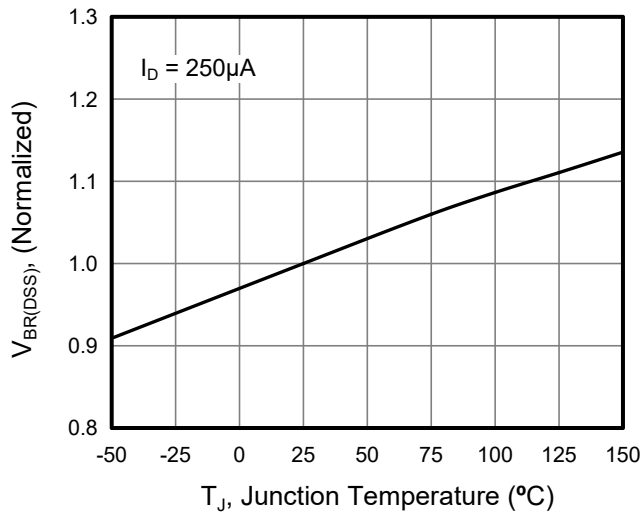


Figure A: Gate Charge Test Circuit and Waveform

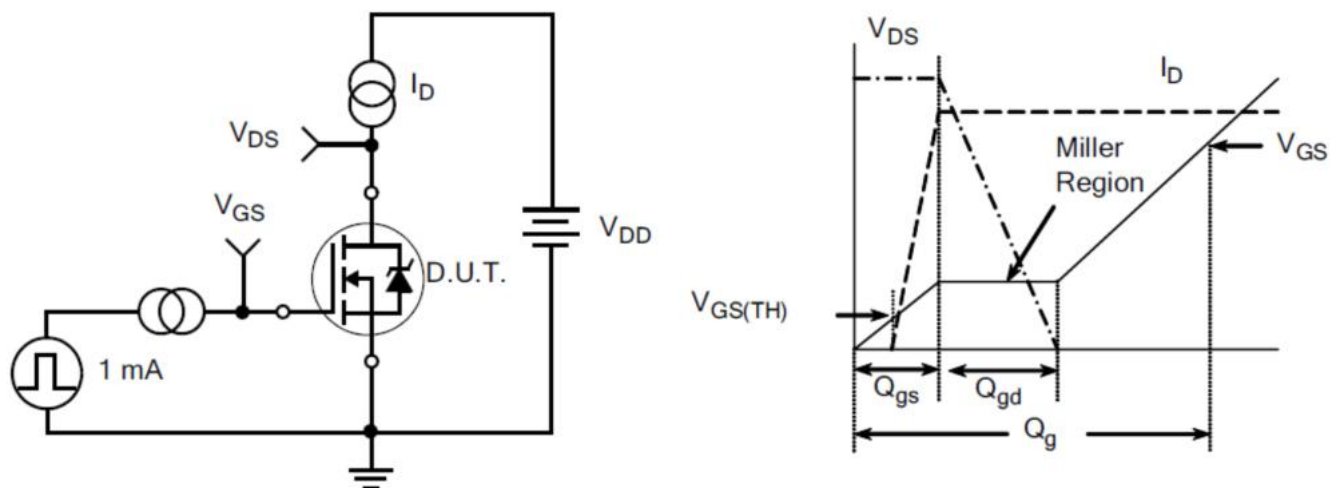


Figure B: Resistive Switching Test Circuit and Waveform

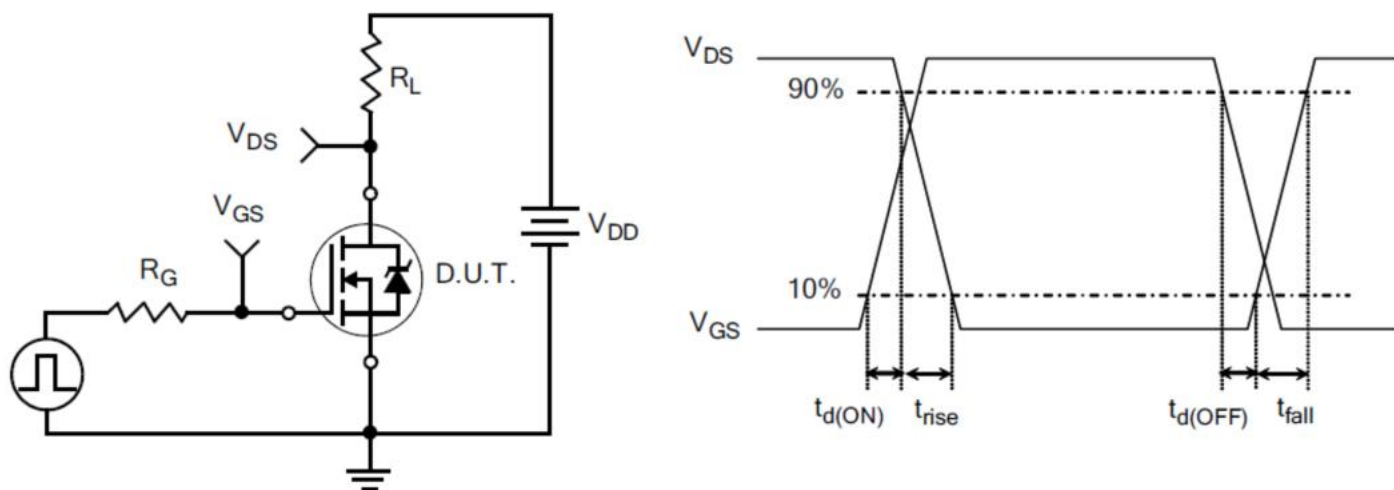
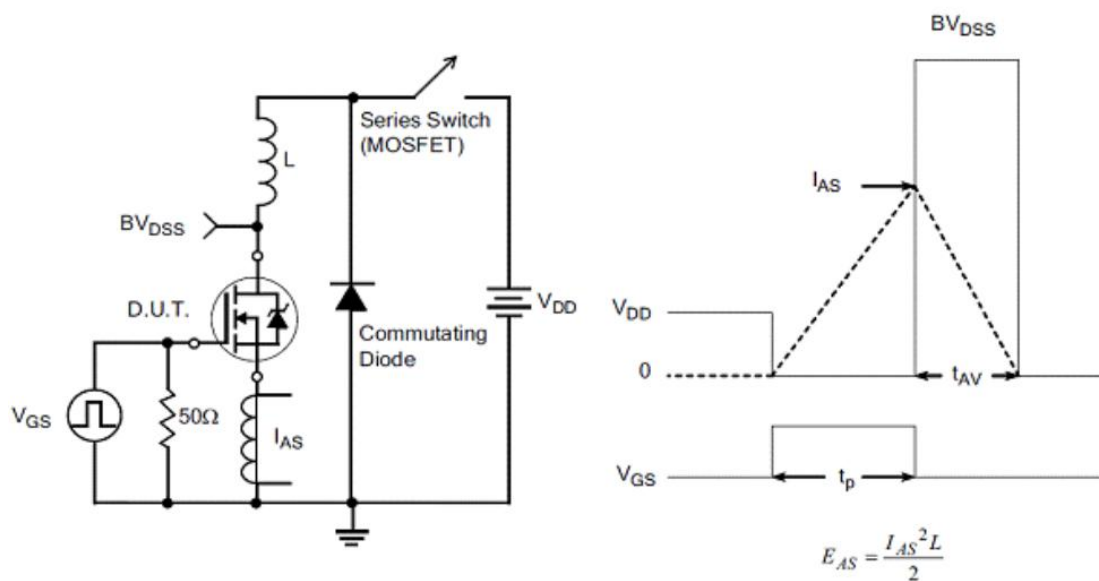
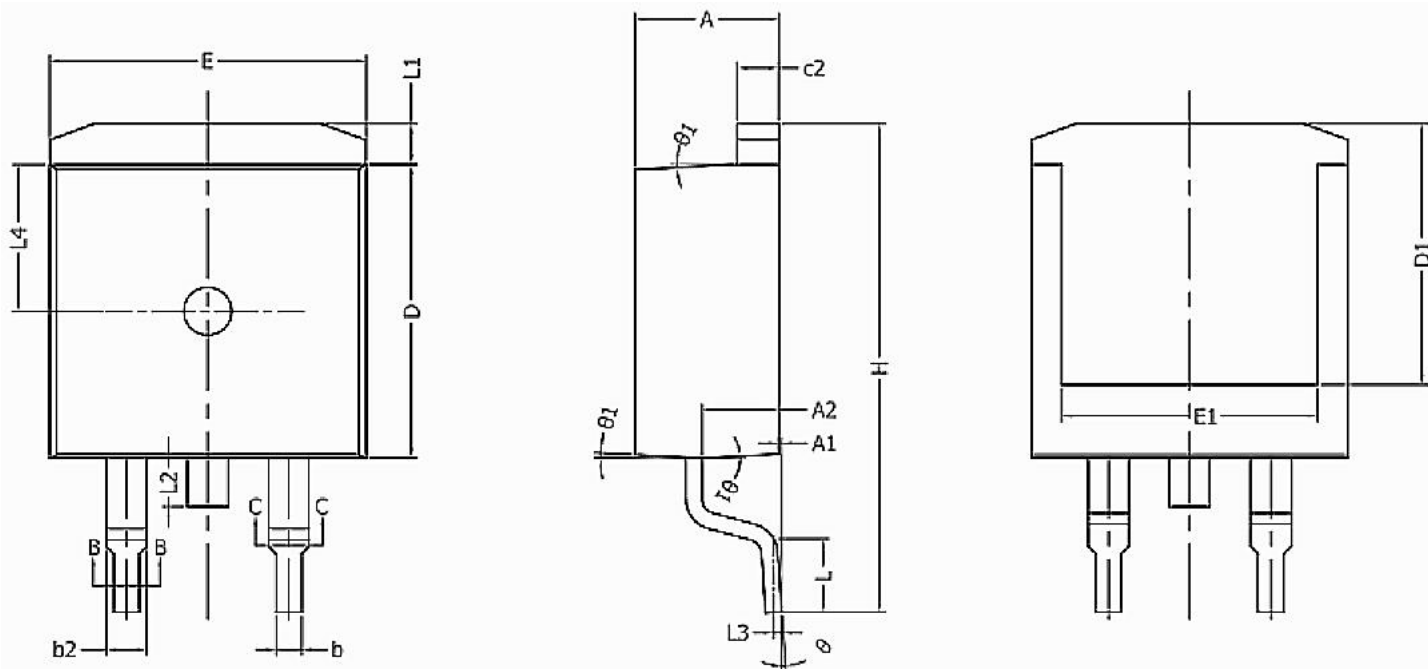


Figure C: Unclamped Inductive Switching Test Circuit and Waveform





## TO-263



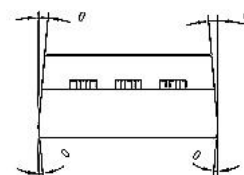
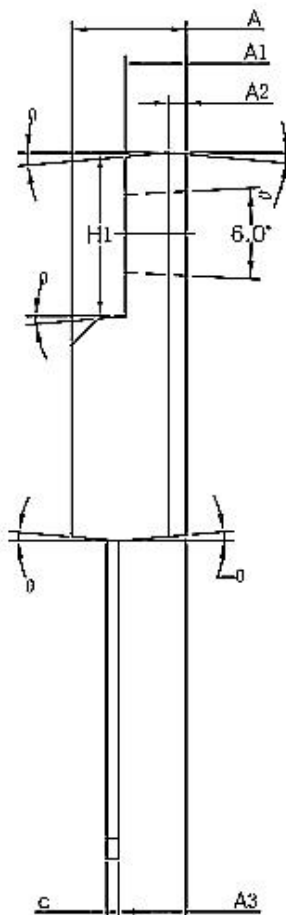
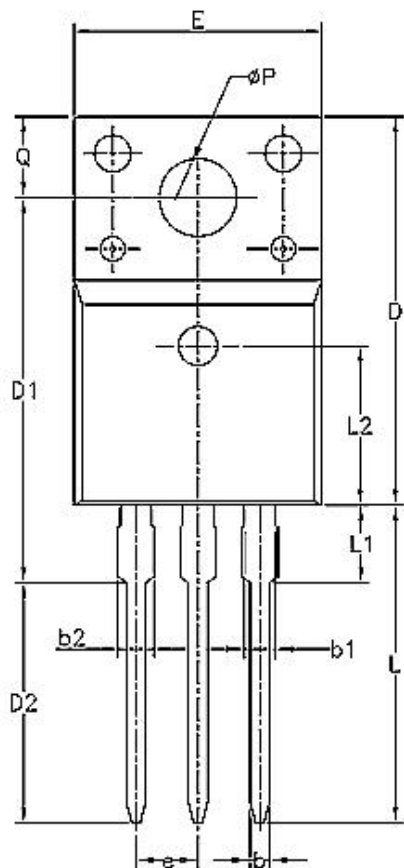
Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	0	0.10	0.25
A2	2.20	2.40	2.60
b	0.76	---	0.89
b1	0.75	0.80	0.85
b2	1.23	---	1.37
b3	1.22	1.27	1.32
c	0.47	---	0.60
c1	0.46	0.51	0.56
c2	1.25	1.30	1.35
D	9.10	9.20	9.30

Unit:mm			
Symbol	Min.	Nom	Max.
D1	8.00	---	---
E	9.80	9.90	10.00
E1	7.80	---	---
e	2.54 BSC		
H	14.90	15.30	15.70
L	2.00	2.30	2.60
L1	1.17	1.27	1.40
L2	---	---	1.75
L3	0.25 BSC		
L4	4.60 REF		
$\theta$	0°	---	8°
$\theta_1$	1°	3°	5°

### Ordering information For TO-263

Package	Units/Tape	Tapes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-263	800	1	800	10	8000

## TO-220F



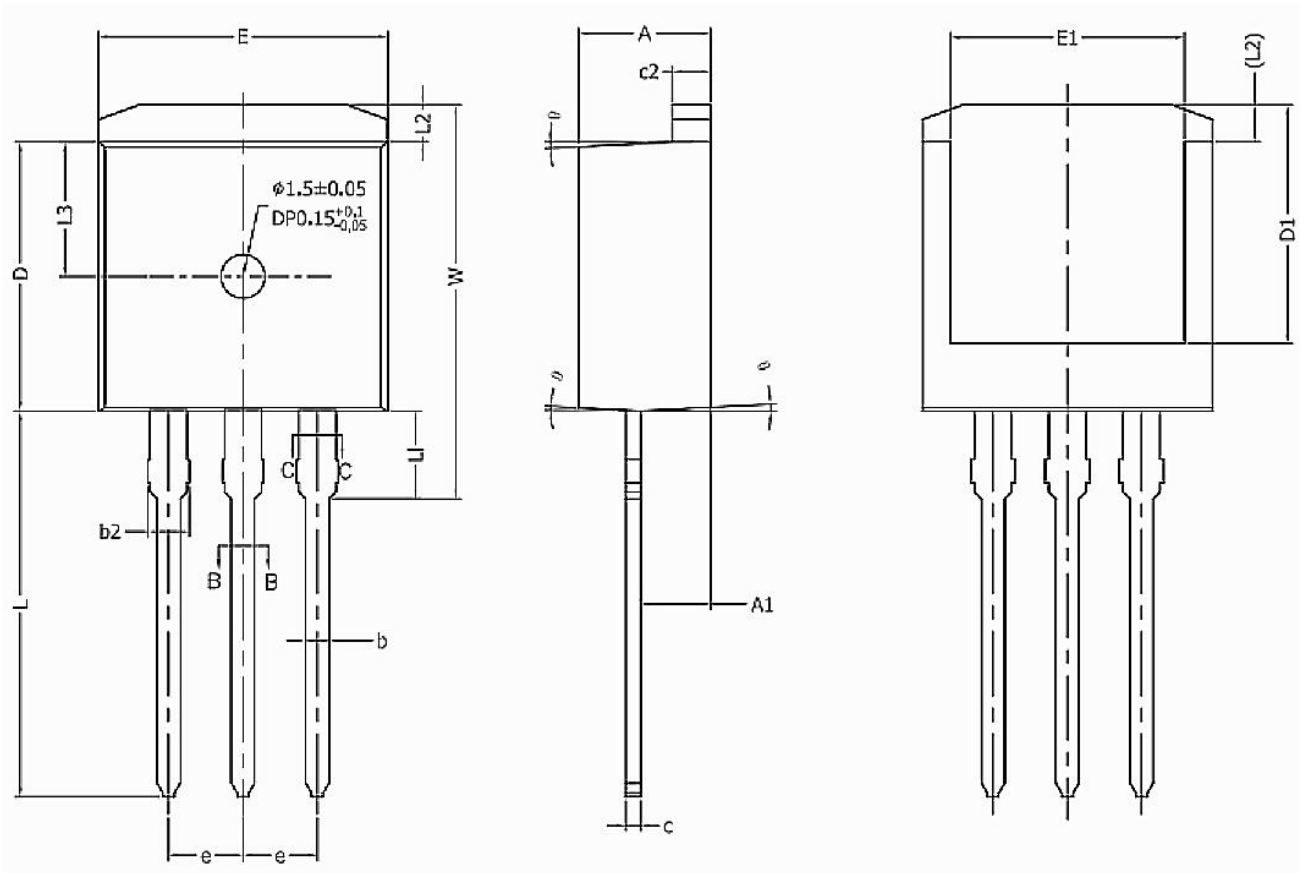
Unit:mm			
Symbol	Min.	Nom	Max.
A	4.50	4.70	4.83
A1	2.34	2.54	2.74
A2	0.70 REF		
A3	2.56	2.76	2.93
b	0.70	---	0.90
b1	1.18	---	1.38
b2	---	---	1.47
c	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	15.55	15.75	15.95

Unit:mm			
Symbol	Min.	Nom	Max.
D2	9.60	9.80	10.0
E	9.96	10.16	10.36
e	2.54 BSC		
H1	6.48	6.68	6.88
L	12.68	12.98	13.28
L1	---	---	3.50
L2	6.50 REF		
$\Phi P$	3.08	3.18	3.28
Q	3.20	---	3.40
$\theta_1$	1°	3°	5°

### Ordering information For TO-220F

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-220F	50	40	2000	4	8000

## TO-262



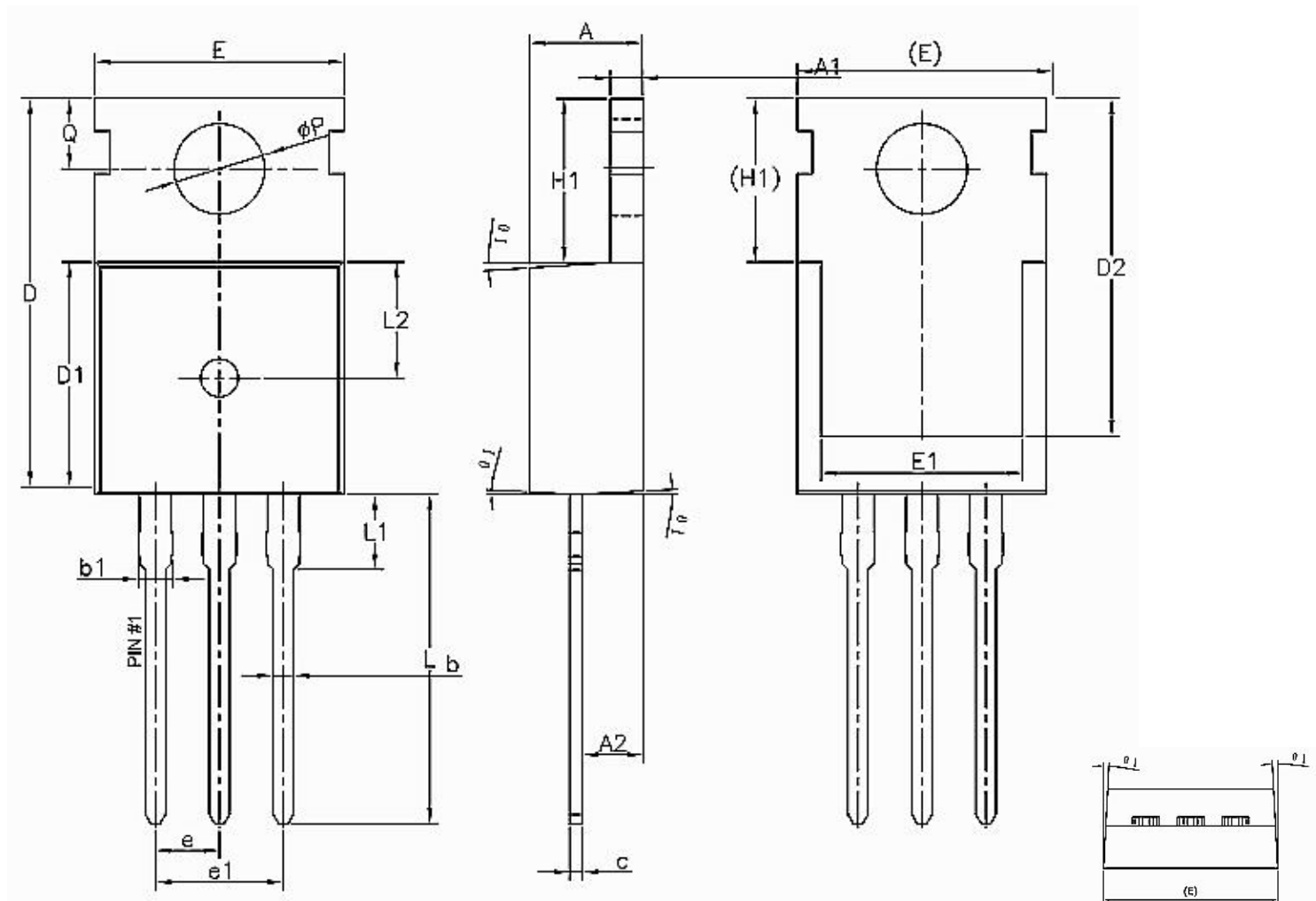
Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	2.20	2.40	2.60
b	0.76	---	0.89
b1	0.75	0.80	0.85
b2	1.23	---	1.37
b3	1.22	1.27	1.32
c	0.47	---	0.60
c1	0.46	0.51	0.56
c2	1.25	1.30	1.35
D	9.10	9.20	9.30

Unit:mm			
Symbol	Min.	Nom	Max.
D1	8.00	---	---
E	9.80	9.90	10.00
E1	7.80	---	---
e	2.54 BSC		
L	12.90	13.20	13.50
L1	2.80	3.00	3.20
L2	1.17	1.27	1.40
L3	4.60 REF		
W	13.25	---	14.00
$\theta$	1°	3°	5°

### Ordering information For TO-262

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-262	50	40	2000	4	8000

## TO-220



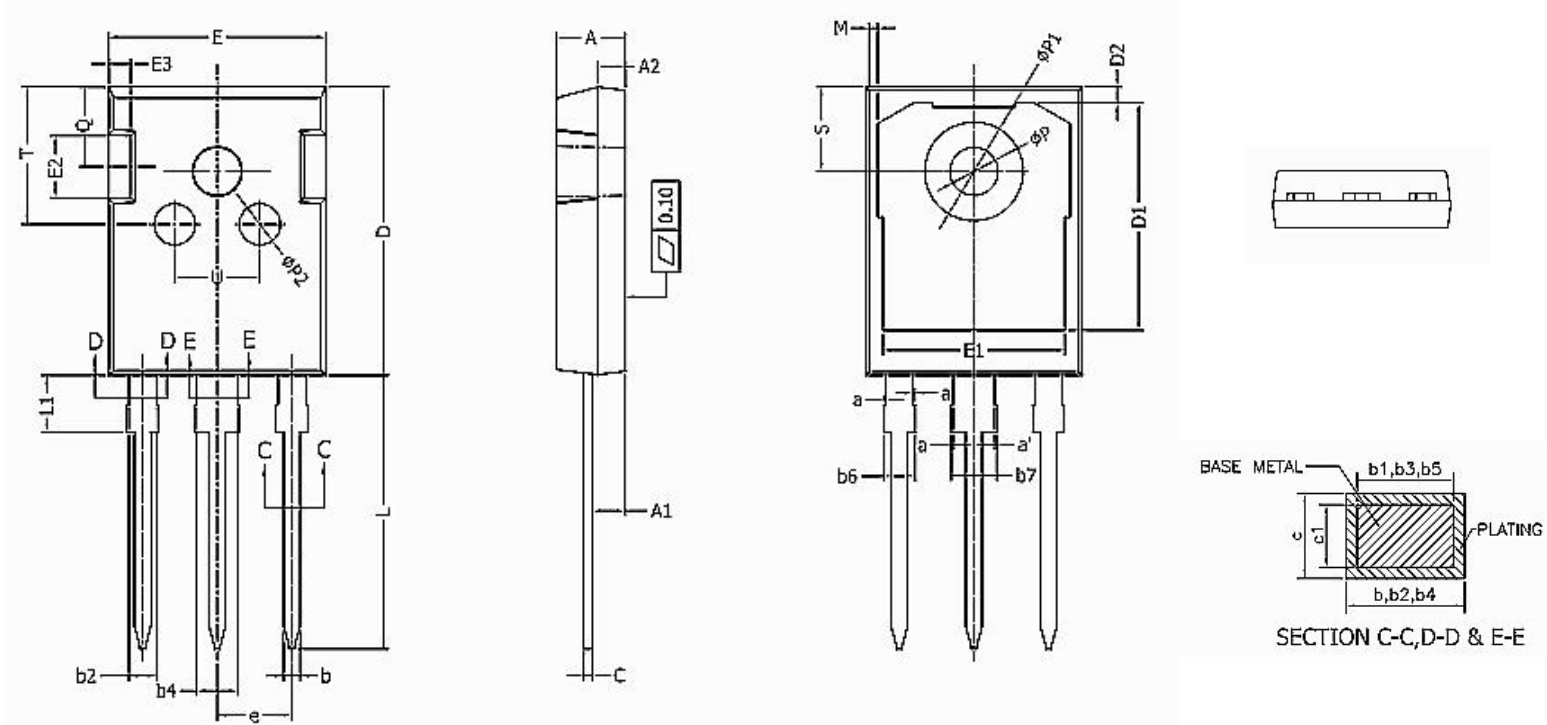
Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	1.27	1.30	1.33
A2	2.30	2.40	2.50
b	0.70	---	0.90
b2	1.27	---	1.40
c	0.45	0.50	0.60
D	15.30	15.70	16.10
D1	9.10	9.20	9.30
D2	13.10	---	13.70
E	9.70	9.90	10.20

Unit:mm			
Symbol	Min.	Nom	Max.
E1	7.80	8.00	8.20
e	2.54 BSC		
e1	5.08 BSC		
H1	6.30	6.50	6.70
L	12.78	13.08	13.38
L1	---	---	3.50
L2	4.60 REF		
ΦP	3.55	3.60	3.65
Q	2.73	---	2.87
θ1	1°	3°	5°

### Ordering information For TO-220

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-220	50	40	2000	4	8000

# TO-247



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.90	5.00	5.10
A1	2.31	2.41	2.51
A2	1.90	2.00	2.10
a	0	---	0.15
a'	0	---	0.15
b	1.16	---	1.26
b1	1.15	1.2	1.22
b2	1.96	---	2.06
b3	1.95	2.00	2.02
b4	2.96	---	3.06
b5	2.96	3.00	3.02
b6	---	---	2.25
b7	---	---	3.25
c	0.59	---	0.66
c1	0.58	0.60	0.62
D	20.90	21.00	21.10
D1	16.25	16.55	16.85

Unit:mm			
Symbol	Min.	Nom.	Max.
D2	1.05	1.17	1.35
E	15.70	15.80	15.90
E1	13.10	13.30	13.50
E2	4.40	4.50	4.60
E3	2.40	2.50	2.60
e	5.436 BSC		
L	19.80	19.92	20.10
L1	---	---	4.30
M	0.35	---	0.95
P	3.40	3.50	3.60
P1	7.00	---	7.40
P2	2.40	2.50	2.60
Q	5.60	---	6.00
S	6.05	6.15	6.25
T	9.80	---	10.20
U	6.00	---	6.40

## Ordering information For TO-247

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-247	30	20	600	5	3000

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.